

1-Line, Unidirectional Transient Voltage Suppressors

Descriptions

The ESD18B250TR is a Unidirectional TVS (Transient Voltage Suppressor). It is specifically designed to protect sensitive electronic components that may be subjected to ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning. It is particularly well-suited for cellular phones, portable device, digital cameras, power supplies and many other portable applications because of its small package and low weight.

The ESD18B250TR may be used to provide ESD protection up to $\pm 30\text{kV}$ air discharge $\pm 30\text{kV}$ contact discharge according to IEC61000-4-2, and withstand peak pulse current up to 6.0A (8/20 μs) according to IEC61000-4-5.

The ESD24B300TR is available in SOD-523 package. Standard products are Pb-free and Halogen-free.

Features

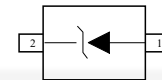
- Stand-off voltage: 18V Max
- Transient protection for each line according to
IEC61000-4-2 (ESD): $\pm 30\text{kV}$ air discharge $\pm 30\text{kV}$ contact discharge
IEC61000-4-4 (EFT): 40A (5/50ns)
IEC61000-4-5 (surge): 6.0A (8/20 μs)
- Solid-state silicon technology
- Low leakage current

Applications

- Cell phone handsets and accessories
- Personal Digital Assistants (PDAs)
- Notebooks, Desktops, and Servers
- Portable Instrumentation
- Digital Cameras
- MID/CAR DVD/MP3/MP4/PMP Players



SOD-523



Circuit diagram

Order information

Device	Package	Shipping
ESD18B250TR	SOD-523	3000/Tape&Reel

Absolute maximum ratings

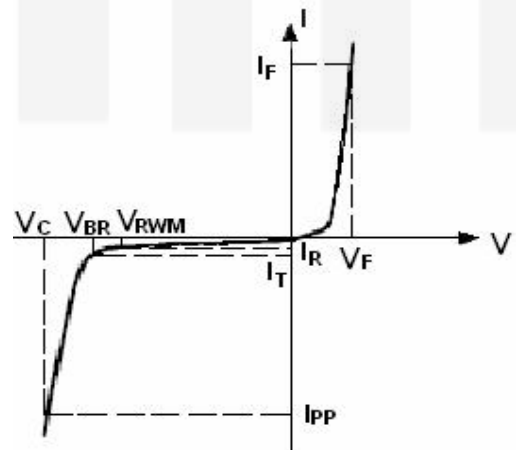
Parameter	Symbol	Rating	Unit
Peak pulse current ($t_p = 8/20\mu s$)	I_{PP}	6.0	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	kV
ESD according to IEC61000-4-2 contact discharge		± 30	
Operation junction temperature	T_J	-55~150	$^{\circ}C$
Lead temperature	T_L	260	$^{\circ}C$
Storage temperature	T_{STG}	-55~150	$^{\circ}C$

Electrical characteristics (TA=25 $^{\circ}C$, unless otherwise noted)

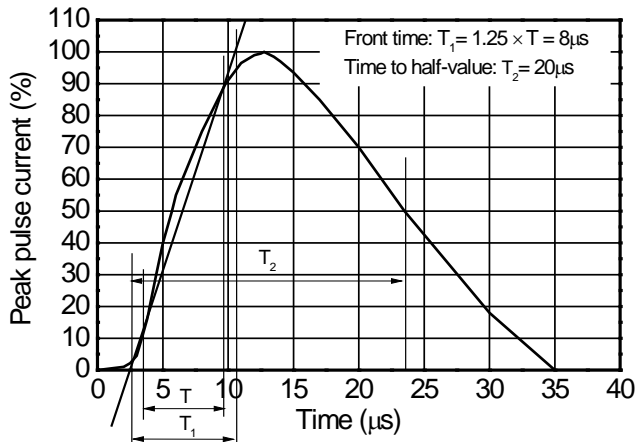
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				18.0	V
Reverse leakage current	$I_{R \text{ pin2-pin1}}$	$V_{RWM} = 18V$			1.0	μA
Reveres breakdown voltage	$V_{BR \text{ pin2-pin1}}$	$I_T = 1mA$	22.0	26.0	30.0	V
Clamping voltage	V_C pin2-pin1	$I_{pp} = 1A \ t_p = 8/20\mu s$		30.0		
		$I_{pp} = 6.0A \ t_p = 8/20\mu s$			50.0	V
Junction capacitance	C_J	$V_R = 0V, f = 1MHz$		25.0	45.0	pF

Electrical performance curve

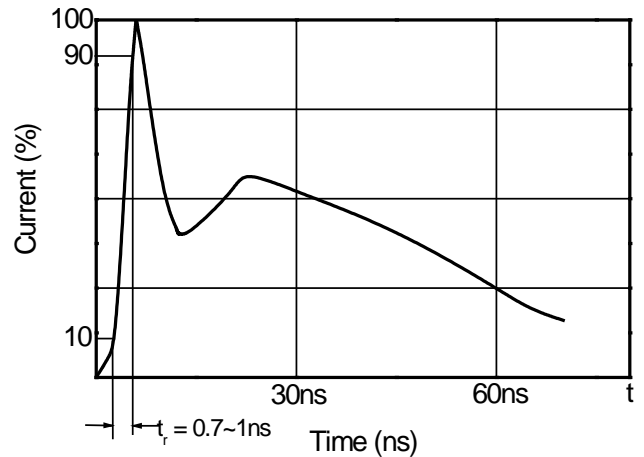
Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
I_T	Test Current
V_{BR}	Breakdown Voltage @ I_T
I_F	Forward Current
V_F	Forward Voltage @ I_F



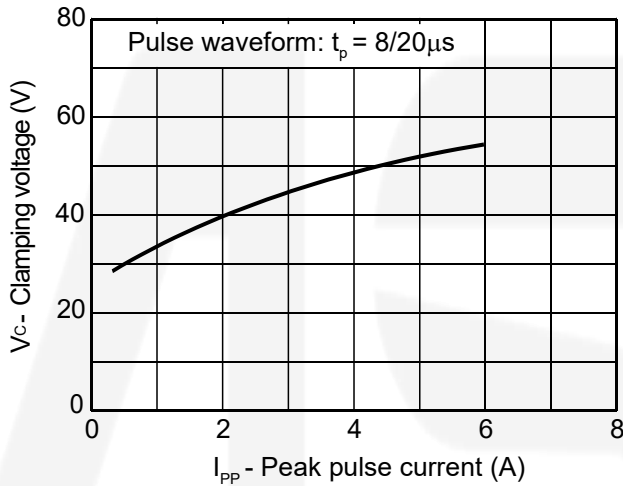
Typical characteristics ($T_A=25^\circ\text{C}$, unless otherwise noted)



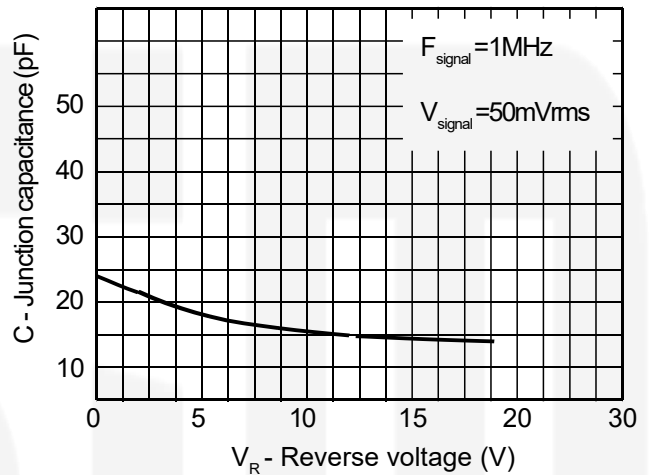
8/20 μs waveform per IEC61000-4-5



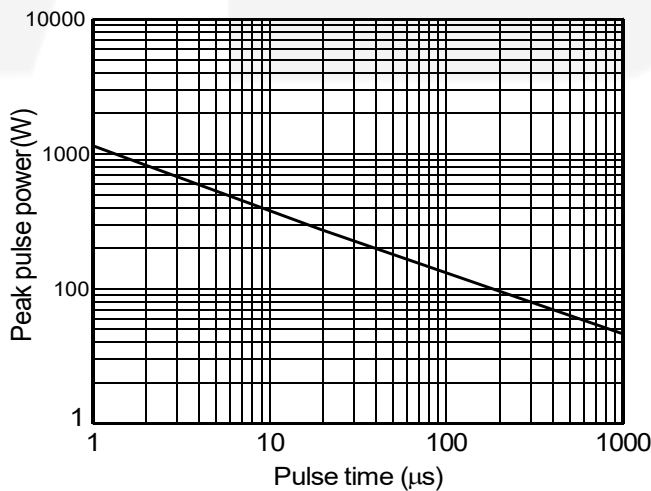
Contact discharge current waveform per IEC61000-4-2



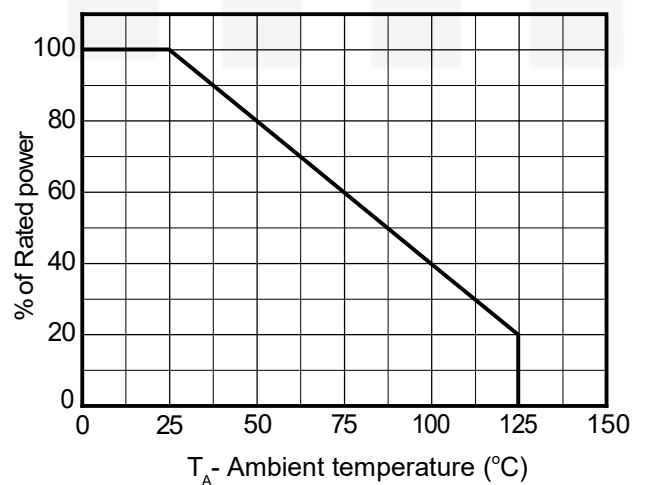
Clamping voltage vs. Peak pulse current



Capacitance vs. Reverses voltage

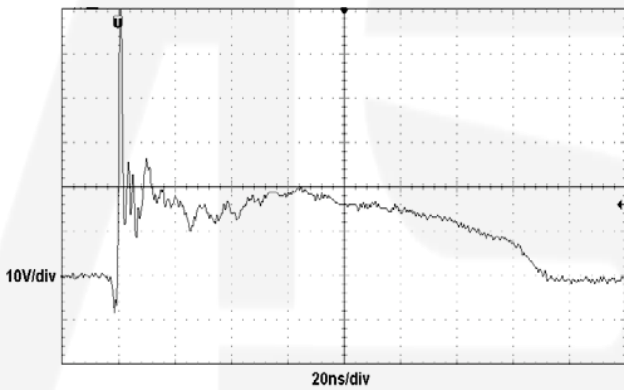
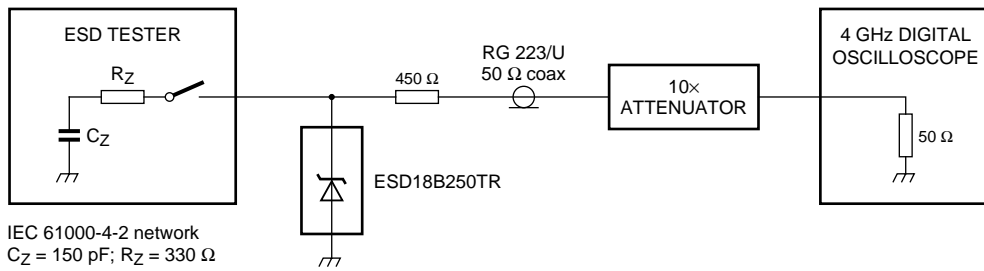


Non-repetitive peak pulse power vs. Pulse time

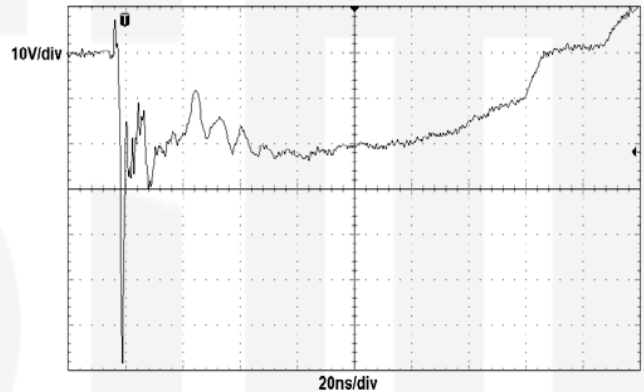


Power derating vs. Ambient temperature

ESD clamping test setup and waveforms



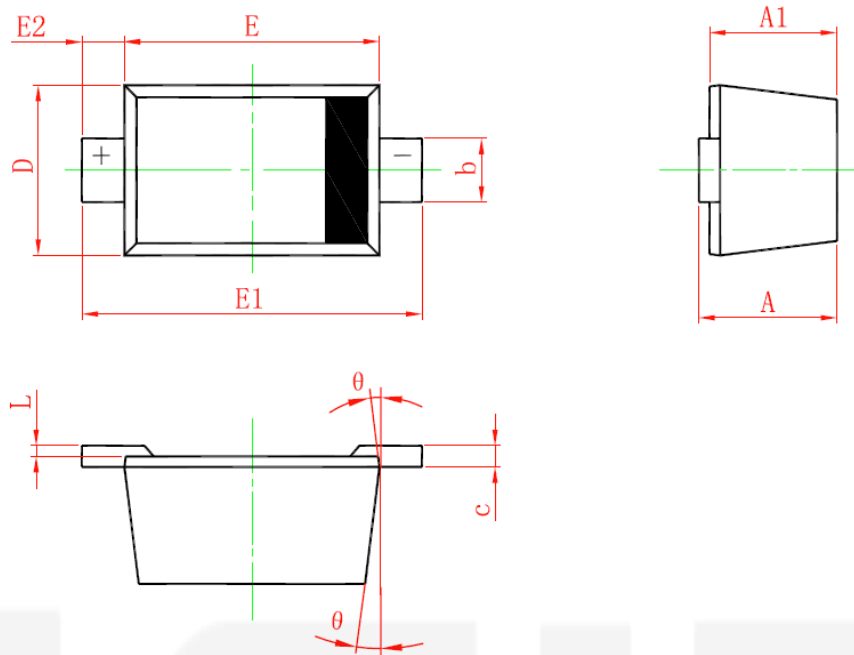
ESD clamping
(+8kV contact discharge per IEC61000-4-2)



ESD clamping
(-8kV contact discharge per IEC61000-4-2)

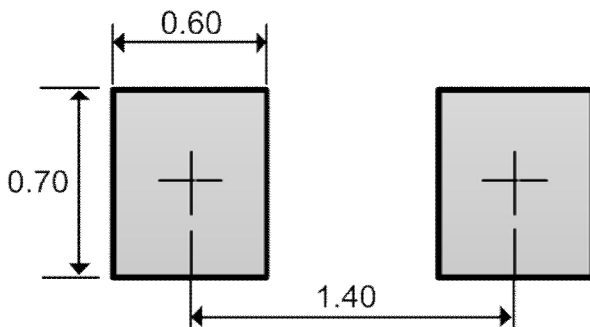
Package outline dimensions

SOD-523



Symbol	Dimensions in millimeter		
	Min.	Typ.	Max.
A	0.510	0.640	0.770
A1	0.500	0.600	0.700
b	0.250	0.300	0.350
c	0.080	0.115	0.150
D	0.750	0.800	0.850
E	1.100	1.200	1.300
E1	1.500	1.600	1.700
E2	0.200 Ref		
L	0.010	0.040	0.070
θ	7° Ref		

Recommend land pattern (Unit: mm)



Note: This land pattern is for your reference only. Actual pad layouts may vary depending on application.